



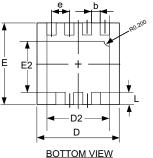
B3L30LP

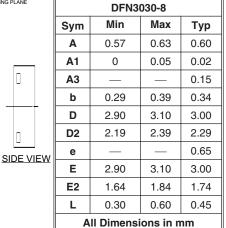
3A SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- High Forward Surge Current Capability
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Device (Note 3)

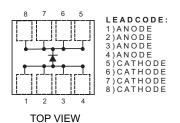
A3 SEATING PLANE SIDE VIEW e h





Mechanical Data

- Case: DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish NiPdAu annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 @3
- Polarity: See Diagram
- Marking: S33 (See Page 3)
- Weight: 0.0172 grams (approximate)



Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	٧
RMS Reverse Voltage	V _{R(RMS)}	21	V
Average Rectified Output Current	I _O	3.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I _{FSM}	30	А

Thermal Characteristics

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance Junction to Soldering Point	R ₀ JS	_	3	°C/W
Thermal Resistance Junction to Ambient Air (Note 2)	$R_{\theta JA}$	130	_	°C/W
Power Dissipation (Note 2)	PD	_	0.75	W
Operating Temperature Range	Tj	-65 to +150		
Storage Temperature Range	T _{STG}	-65 to +150		

Notes:

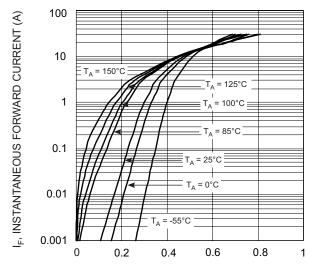
- 1. RoHS revision 13.2.2003. Glass and High Temperature Solder Exemptions Applied, see EU Directive Annex Notes 5 and 7.
- 2. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf. TA = 25°C.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.



Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 4)	V _{(BR)R}	30	_	_	V	I _R = 5.0mA
Forward Voltage	VF		0.30 0.18 0.33 0.22 0.35 0.26	0.35 0.29 0.40 0.37 0.45 0.42	V	$\begin{array}{l} I_F = 1.0A, T_j = 25^{\circ}C \\ I_F = 1.0A, T_j = 125^{\circ}C \\ I_F = 2.0A, T_j = 25^{\circ}C \\ I_F = 2.0A, T_j = 125^{\circ}C \\ I_F = 3.0A, T_j = 25^{\circ}C \\ I_F = 3.0A, T_j = 125^{\circ}C \end{array}$
Reverse Current (Note 4)	I _R		0.27 55	1.0 90	mA mA	$T_j = 25$ °C, $V_R = 30V$ $T_j = 100$ °C, $V_R = 30V$

Notes: 4. Short duration test pulse used to minimize self-heating effect.



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 1 Typical Forward Characteristics

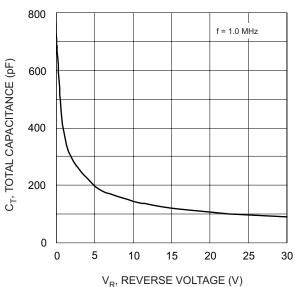


Fig. 3 Typical Total Capacitance vs. Reverse Voltage

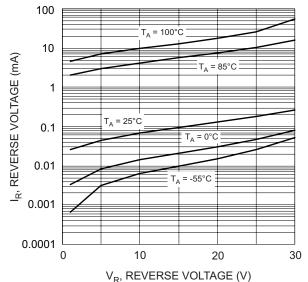
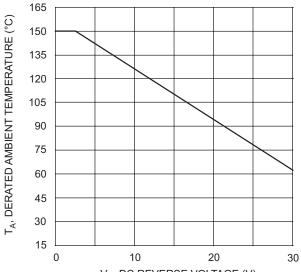


Fig. 2 Typical Reverse Characteristics



V_R, DC REVERSE VOLTAGE (V) Fig. 4 Operating Temperature Derating

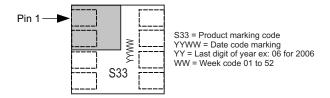


Ordering Information (Note 5)

Device	Packaging	Shipping
B3L30LP-7	DFN3030-8	3,000/Tape & Reel

Notes: 5. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



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